

# LM185/LM285/LM385 Adjustable Micropower Voltage References

### **General Description**

The LM185/LM285/LM385 are micropower 3-terminal adjustable band-gap voltage reference diodes. Operating from 1.24 to 5.3V and over a  $10\mu A$  to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185 band-gap reference uses only transistors and resistors, low noise and good long-term stability result.

Careful design of the LM185 has made the device tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the

wide operating current allows it to replace older references with a tighter tolerance part.

The LM185 is rated for operation over a –55°C to 125°C temperature range, while the LM285 is rated –40°C to 85°C and the LM385 0°C to 70°C. The LM185 is available in a hermetic TO-46 package and a leadless chip carrier package, while the LM285/LM385 are available in a low-cost TO-92 molded package, as well as S.O.

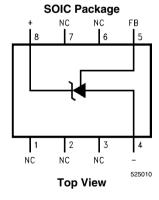
### **Features**

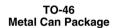
- Adjustable from 1.24V to 5.30V
- Operating current of 10µA to 20mA
- 1% and 2% initial tolerance
- 1Ω dynamic impedance
- Low temperature coefficient

### **Connection Diagrams**

TO-92 Plastic Package

Bottom View

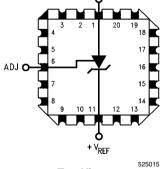






Bottom View

20-Leadless Chip Carrier

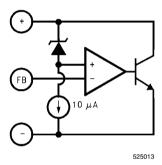


**Top View** 

# **Ordering Information**

Package	Temperature Range						
-55°C to 125°C	–40°C to 85°C	0°C to 70°C					
	LM185BH						
TO-46	LM185BH/883			110011			
10-46	LM185BYH			H03H			
	LM185BYH/883						
		LM285BXZ	LM385BXZ				
TO 00		LM285BYZ	LM385BYZ	7004			
TO-92		LM285Z	LM385BZ	Z03A			
			LM385Z				
8-Pin SOIC		LM285M	LM385M	MOGA			
		LM285BYM	LM385BM	— M08A			
20-Leadless Chip Carrier	LM185BE/883			E20A			

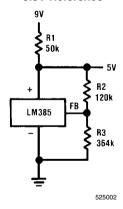
# **Block Diagram**



# **Typical Applications**

# 1.2V Reference 9V R1 500k LM385 FB 525014

### 5.0V Reference



$$V_{OUT} = 1.24 \left( \frac{R3}{R2} + 1 \right)$$

### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Reverse Current 30mA **Forward Current** 10mA

Operating Temperature Range (Note 3)

LM185 Series -55°C to 125°C LM285 Series -40°C to 85°C 0°C to 70°C LM385 Series

ESD Susceptibility (Note 8) 2kV Storage Temperature -55°C to 150°C

Soldering Information

260°C TO-92 Package (10 sec.) 300°C TO-46 Package (10 sec.)

SO Package

Vapor Phase (60 sec.) 215°C 220°C Infrared (15 sec.)

See An-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering

surface mount devices.

### **Electrical Characteristics** (Note 4)

		LM185, LM285					LM385					
Parameter	Conditions	Тур	LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285		Тур	LM385BX, LM385BY		LM385		Units (Limit)
				Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	.,,,,	Tested Limit (Note 5)	Design Limit (Note 6)	Tested Limit (Note 5)	Design Limit (Note 6)	<b>⊣</b> ` ′
Reference	I <sub>R</sub> = 100μA	1.240	1.252	- /	1.265	1.270	1.240	1.252	1.255	1.265	1.270	V
Voltage			<b>1.255</b> 1.228 <b>1.215</b>		1.215	1.205		1.228	1.215	1.215	1.205	(max) V (min)
Reference Voltage	I <sub>MIN</sub> < I <sub>R</sub> < 1mA	0.2	1	1.5	1	1.5	0.2	1	1.5	1	1.5	mV
Change with Current	1mA < I <sub>R</sub> < 20mA	4	10	20	10	20	5	15	25	15	25	(max)
Dynamic Output Impedance	$\begin{split} I_R &= 100 \mu A, & f = \\ & 100 Hz \\ I_{AC} &= 0.1 \ I_R & V_{OUT} = \\ & V_{REF} \\ & V_{OUT} = \\ & 5.3 V \end{split}$	0.3					0.4					Ω
Reference Voltage Change with Output Voltage	I <sub>R</sub> = 100μA	1	3	6	3	6	2	5	10	5	10	mV (max)
Feedback Current		13	20	25	20	25	16	30	35	30	35	nA (max)
Minimum Operating Current (see	$V_{OUT} = V_{REF}$ $V_{OUT} = 5.3V$	6 30	9 45	10 50	9 45	10 50	7 35	11 55	13 60	11 55	13 60	μA (max)
curve) Output Wideband	I <sub>R</sub> = 100μA, 10Hz < f < 10kHz											
Noise	$V_{OUT} = V_{REF}$ $V_{OUT} = 5.3V$	50 170					50 170					$\mu V_{rms}$

			LM185, LM285				LM385						
Parameter	Conditions Typ		Тур	LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285		Тур	LM385BX,		LM385		Units (Limit)
				Tested	Design	Tested	Design	T T	Tested	Design	Tested	Design	
				Limit	Limit	Limit	Limit		Limit	Limit	Limit	Limit	
				(Note	(Note	(Note	(Note		(Note	(Note	(Note	(Note	
				5)	6)	5)	6)		5)	6)	5)	6)	
Average Temperature	I <sub>R</sub> = 100μA	X Suffix		30					30				ppm/°
Coefficient		Y Suffix		50					50				(max)
(Note 7)													
		All			150		150			150		150	
		Others											
Long Term Stability	I <sub>R</sub> = 100μA, ٦ Hr,	Γ = 1000	20					20					ppm
	T <sub>A</sub> = 25°C ±	0.1°C											

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H for military specifications.

Note 3: For elevated temperature operation, T<sub>.</sub>max is:

LM185 150°C LM285 125°C LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	
θ <sub>JA</sub> (Junction to Ambient)	180°C/W (0.4 leads)	440°C/W	165°C/W	
	170°C/W (0.125 leads)			
θ <sub>JC</sub> (Junction to Case)	N/A	80°C/W	N/A	

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25$ °C. Unless otherwise specified, all parameters apply for  $V_{REF} < V_{OUT} < 5.3V$ .

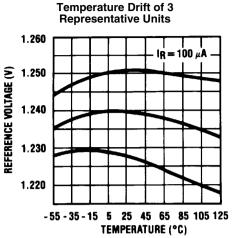
Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not to be used to calculate average outgoing quality levels.

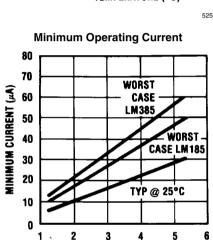
Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures from T<sub>MIN</sub> to T<sub>MAX</sub>, divided by T<sub>MAX</sub> – T<sub>MIN</sub>. The measured temperatures are –55, –40, 0, 25, 70, 85, 125°C.

Note 8: The human body model is a 100 pF capacitor discharged through a 1.5 k $\Omega$  resistor into each pin.

# **Typical Performance Characteristics**

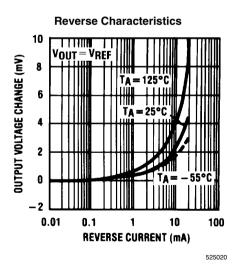


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**OUTPUT VOLTAGE (V)** 

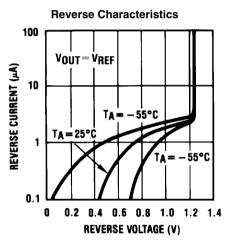
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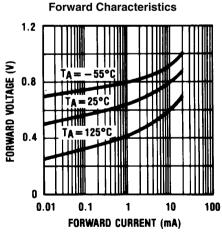
**Feedback Current** 25  $IR = 100 \mu A$ FEEDBACK CURRENT (nA) 20 15 Vout = VREF 10 = 5.3V Vouт 5 0 -50 - 250 25 50 75 100 125

TEMPERATURE (°C)

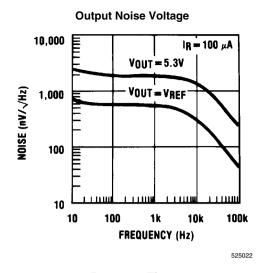
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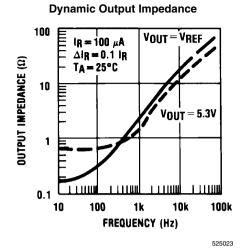


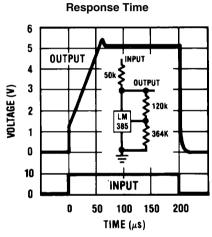
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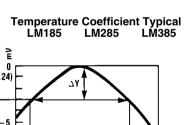


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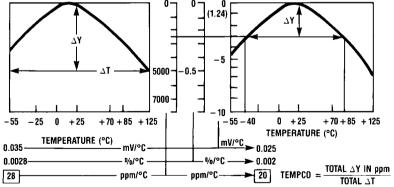




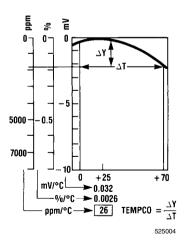




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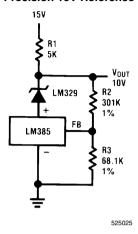


mdd

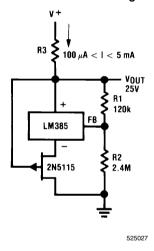


# **Typical Applications**

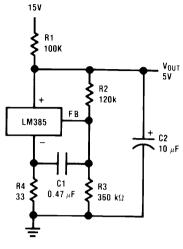
### **Precision 10V Reference**



### 25V Low Current Shunt Regulator

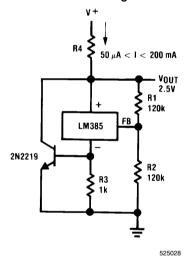


### **Low AC Noise Reference**

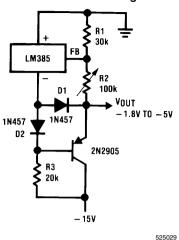


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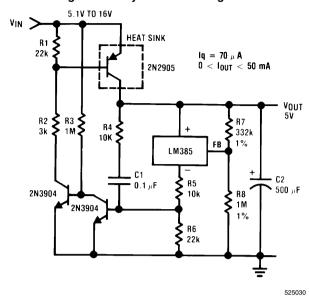
### 200 mA Shunt Regulator



### Series-Shunt 20 mA Regulator

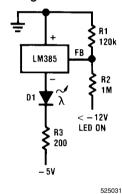


### **High Efficiency Low Power Regulator**

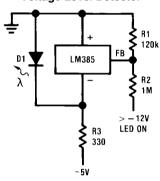


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### **Voltage Level Detector**

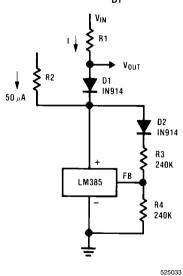


### **Voltage Level Detector**

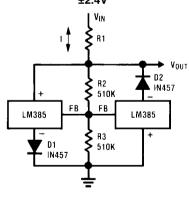


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# Fast Positive Clamp $2.4V + \Delta V_{D1}$

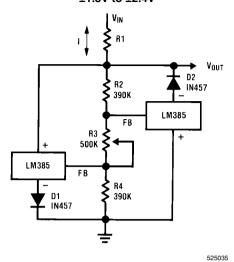


### Bidirectional Clamp ±2.4V

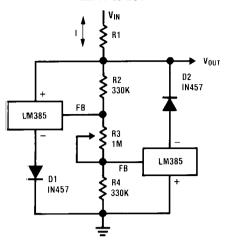


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# Bidirectional Adjustable Clamp ±1.8V to ±2.4V

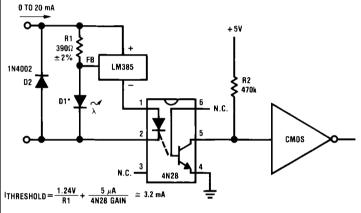


# Bidirectional Adjustable Clamp ±2.4V to ±6V

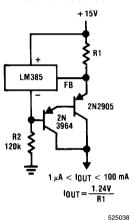


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### **Simple Floating Current Detector**

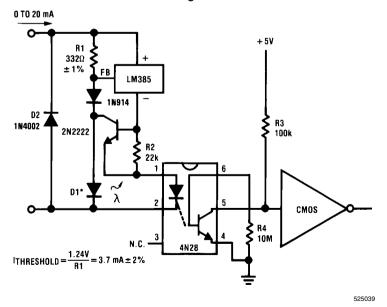


### **Current Source**



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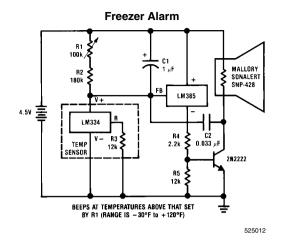
### **Precision Floating Current Detector**



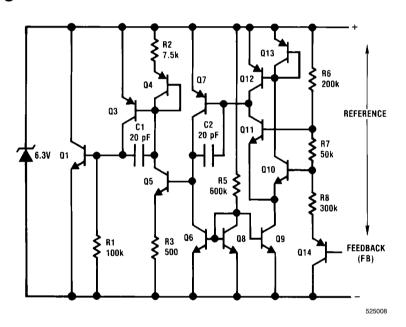
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\*D1 can be any LED,  $V_F$ =1.5V to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if  $I_{THRESHOLD}$  falls below the threshold current, except with I=O.

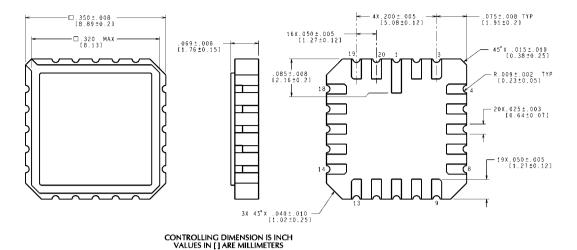
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# **Schematic Diagram**

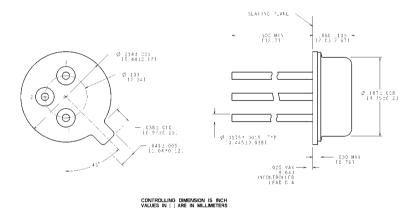


# Physical Dimensions inches (millimeters) unless otherwise noted



20-Leadless Chip Carrier (E) NS Package Number E20A

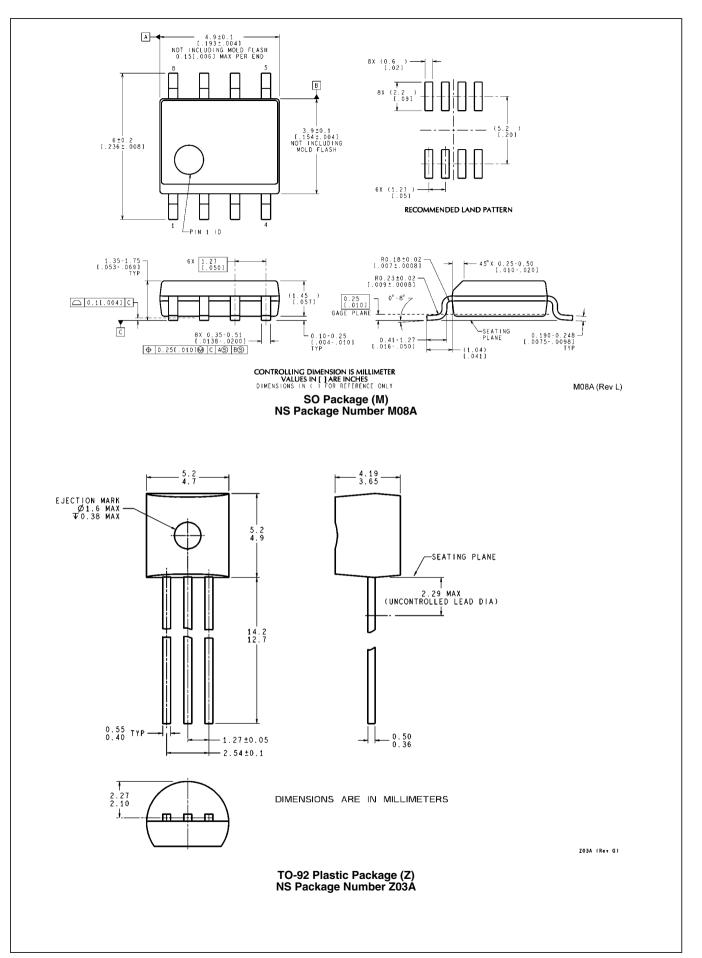
E20A (Rev F)



TO-46 Metal Can Package (H) NS Package Number H03H

11 www.national.com

H03H (Rev F)



### **Notes**

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